

GaAs Transfer Switch, DC-3.0 GHz

Rev. V5

#### **Features**

- Small Ceramic Package, 0.250" Sq.
- · Fast Switching Speed, 4 ns Typical
- Ultra Low DC Power Consumption
- 50 Ohm Nominal Impedance
- MIL-STD-883 screening available
- Lead-Free CR-4 Package
- 260°C Reflow Compatible
- RoHS\* Compliant

#### Description

M/A-COM's SW-283-PIN is a GaAs MMIC transfer switch packaged in lead-free, surface mount CR-4 ceramic style packages. SW-283-PIN offers low insertion loss, high isolation, and fast switching. This ceramic switch platform has a common footprint for all three designs. The CR-4 package is hermetically sealed, making this switch ideal for space, military radios, and other environmentally harsh applications.

Typical applications include synthesizer switching, transmit/receive switching, switch matrices and filter banks in systems such as radio and cellular equipment, PCM, GPS, and fiber optic modules.

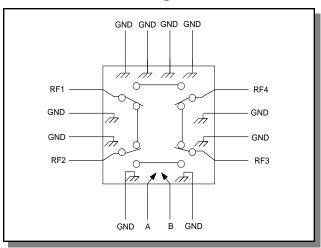
The SW-283-PIN transfer switch contains a monolithic GaAs MMIC which is fabricated using a 1.0 micron MESFET process.

### **Ordering Information**

Part Number	Package
SW-283-PIN	Bulk Packaging

Note: Reference Application Note M513 for reel size information.

### **Functional Block Diagram**



#### **Pin Configuration**

Pin No.	Function	Pin No.	Function
1	RF1	9	RF3
2	GND	10	GND
3	GND	11	GND
4	RF2	12	RF4
5	GND	13	GND
6	А	14	GND
7	В	15	GND
8	GND	16	GND

The metal bottom of the case must be connected to RF and DC ground.

<sup>\*</sup> Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

# **SW-283-PIN**



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# Electrical Specifications: $T_A = 25$ °C, $Z_0 = 50\Omega^{1,2}$

Parameter	Test Conditions	Frequency	Units	Min	Тур	Max
Insertion Loss	_	DC - 3 GHz DC - 2 GHz DC - 1 GHz DC - 0.5 GHz	dB dB dB dB	_ _ _ _	_ _ _ _	2.1 1.8 1.3 1.0
VSWR	_	DC - 3 GHz Ratio DC - 2 GHz Ratio DC - 1 GHz Ratio DC - 0.5 GHz Ratio		_ _ _ _	_ _ _ _	1.9:1 1.7:1 1.3:1 1.25:1
Isolation	_	DC - 3 GHz DC - 2 GHz DC - 1 GHz DC - 0.5 GHz	dB dB dB dB	20 25 40 45	_ _ _ _	_ _ _
Trise, Tfall Ton, Toff Transients	10/90% or 90/10% RF 50% CTL to 90/10% RF In-Band	_ _ _	nS nS mV	_ _ _	2 4 30	
1 dB Compression	Control Voltage 0/-5 VDC Control Voltage 0/-8 VDC	0.5 - 3 GHz 0.05 GHz 0.5 - 3 GHz 0.05 GHz	dBm dBm dBm dBm	_ _ _ _	+27 +21 +33 +26	_ _ _ _
IP <sub>2</sub>	For two-tone Input power up to +13 dBm	0.5 - 3 GHz 0.05 GHz	dBm dBm	_	+68 +62	_
IP <sub>3</sub>	For two-tone Input power up to +13 dBm	0.5 - 3 GHz 0.05 GHz	dBm dBm	_	+50 +45	_
Control Voltages	V <sub>IN</sub> Low: 0 to –0.2V V <sub>IN</sub> High: -5V @ 10 μA Typ to –8V		_	_	_	5 μΑ 200 μΑ

<sup>1.</sup> All specifications apply with 50 ohm impedance connected to all RF ports with 0 and -5 VDC control voltages.

# Absolute Maximum Ratings 3,4

Parameter	Absolute Maximum
Input Power 0.05 GHz 0.5 - 3.0 GHz	+27 dBm +34 dBm
Control Voltage	-8.5 V <u>&lt;</u> Vc <u>&lt;</u> +5 V
Operating Temperature	-55°C to +125°C
Storage Temperature	-65°C to +150°C

Exceeding any one or combination of these limits may cause permanent damage to this device.

<sup>2.</sup> Faster switching speed can be achieved with enhanced driver waveform.

M/A-COM does not recommend sustained operation near these survivability limits.

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 Visit www.macomtech.com for additional data sheets and product information.



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#### **Handling Procedures**

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

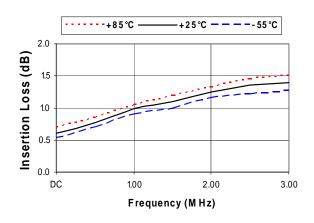
#### **Truth Table (Switch)**

Control Input		Condition of Switch			h
Α	В	RF1- RF2	RF2- RF3	RF1- RF4	RF3- RF4
HI	LOW	OFF	ON	ON	OFF
LOW	HI	ON	OFF	OFF	ON

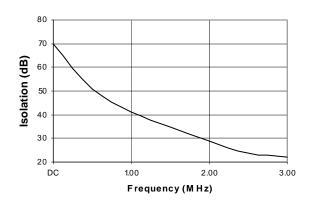
Low = 0.0V, High = -5.0V

## **Typical Performance Curves**

#### Insertion Loss vs. Frequency

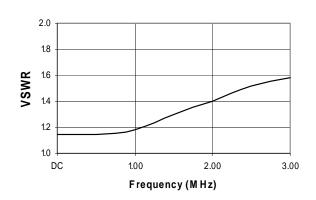


#### Isolation vs. Frequency



#### VSWR vs. Frequency

3



and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology

Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

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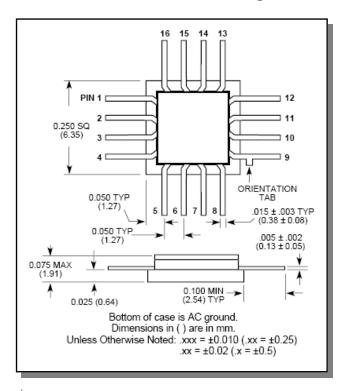
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## Lead-Free, CR-4 Ceramic Package<sup>†</sup>



Reference Application Note M538 for lead-free solder reflow recommendations.

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